



DMN30H14DLY

N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

V _{(BR)DSS}	R _{DS(ON)}	Ι _D T _A = +25°C
2001/	14Ω @ V _{GS} = 10V	0.21A
300V	20Ω @ V _{GS} = 4.5V	0.17A

Description

This new generation MOSFET has been designed to minimize the onstate resistance (R_{DS(ON)}) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- Power management functions
- Battery Operated Systems and Solid-State Relays
- Drivers: Relays, Solenoids, Lamps, Hammers, Displays, Memories, Transistors, etc

Features

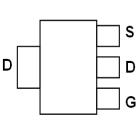
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

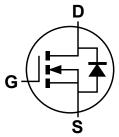
- Case: SOT89
- Case Material: Molded Plastic, "Green" Molding Compound UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Finish annealed over Copper lead frame. Solderable per MIL-STD-202, Method 208@3)
- Weight: 0.052 grams (approximate)



Top View



Pin-out Top



Equivalent Circuit

Ordering Information (Note 4)

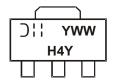
	Part Number	Compliance	Case	Quantity per reel		
	DMN30H14DLY-13	Standard	SOT89	2,500		
Notes:	Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.					

2. See http://www.diodes.com/quality/lead free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product_grade_definitions/.

Marking Information



DII = Manufacturer's Marking H4Y = Marking Code YWW = Date Code Marking Y= Year (ex: 4 = 2014) WW = Week (01 - 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Units
Drain-Source Voltage			V _{DSS}	300	V
Gate-Source Voltage			V _{GSS}	±20	V
Continuous Drain Current (Note 6) V _{GS} = 10V Steady State		T _A = +25°C T _A = +70°C	ID	0.21 0.16	А
Pulsed Drain Current (10µs pulse, duty cycle ≦1%)			I _{DM}	1	А
Maximum Body Diode Continuous Current (Note 6)			I _S	2	А

Thermal Characteristics

Characteristic		Symbol	Value	Units
Total Dower Discinction	(Note 5)	D	0.9	W
Total Power Dissipation	(Note 6)	PD	2.2	
Thermal Desistance, Junction to Ambient	(Note 5)	P	132	°C/W
Thermal Resistance, Junction to Ambient	(Note 6)	$R_{ extsf{ heta}JA}$	55	
Thermal Resistance, Junction to Case (Note 6		R _θ JC	9.6	
Operating and Storage Temperature Range	T _{J,} T _{STG}	-55 to +150	°C	

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	300		_	V	V _{GS} = 0V, I _D = 250µA	
Zero Gate Voltage Drain Current	I _{DSS}	_		1	μA	$V_{DS} = 240V, V_{GS} = 0V$	
Gate-Body Leakage	I _{GSS}	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(th)}	1		3	V	V_{DS} = V_{GS} , I_D = 250 μ A	
Static Drain-Source On-Resistance	Р		6	14	0	V _{GS} = 10V, I _D = 0.3A	
	R _{DS(ON)}	_	6	20	Ω	V _{GS} = 4.5V, I _D = 0.2A	
Diode Forward Voltage	V _{SD}		0.7	1.2	V	V _{GS} = 0V, I _S = 0.3A	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	C _{iss}		96	_		V _{DS} = 25V, V _{GS} = 0V, f = 1MHz	
Output Capacitance	C _{oss}	_	5.8	_	pF		
Reverse Transfer Capacitance	C _{rss}		3.2	_			
Gate Resistance	R _G		12	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$	
Total Gate Charge	Qg		4	_		V _{DS} = 192V, V _{GS} = 10V, I _D = 0.5A	
Gate-Source Charge	Q _{gs}		0.3	_	nC		
Gate-Drain Charge	Q _{gd}		1.9	_			
Turn-On Delay Time	t _{D(on)}		3.3	—			
Turn-On Rise Time	tr		8.6	—		$V_{DS} = 60V, R_{L} = 200\Omega$	
Turn-Off Delay Time	t _{D(off)}	_	22	_	nS	V _{GS} = 10V, R _G = 25Ω	
Turn-Off Fall Time	tf	_	12	—			
Reverse Recovery Time	t _{rr}	_	43	—	nS		
Reverse Recovery Charge	Q _{rr}		47	_	nC	V_R = 100V, I _F =1.0A, di/dt=100A/µs	

Notes: 5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.

Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate
Short duration pulse test used to minimize self-heating effect

8. Guaranteed by design. Not subject to production testing



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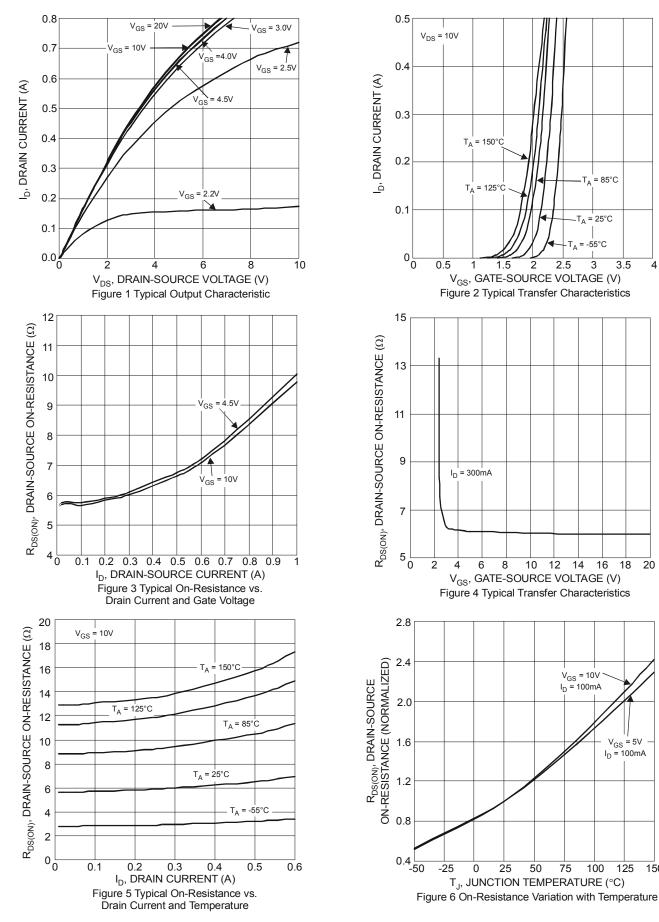
3.5

18 20

V_{GS} = 5V I_D = 100mA

125

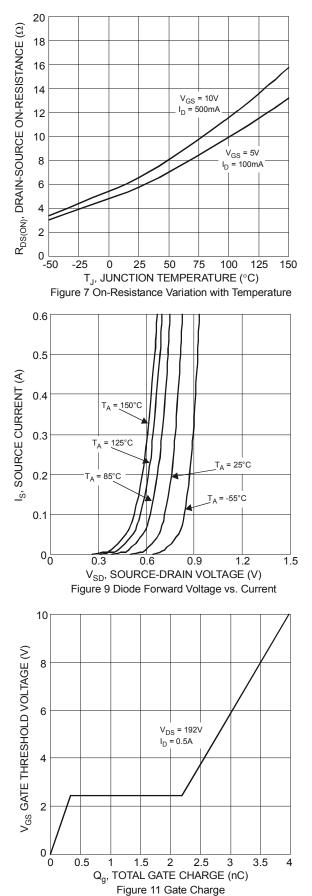
4



150







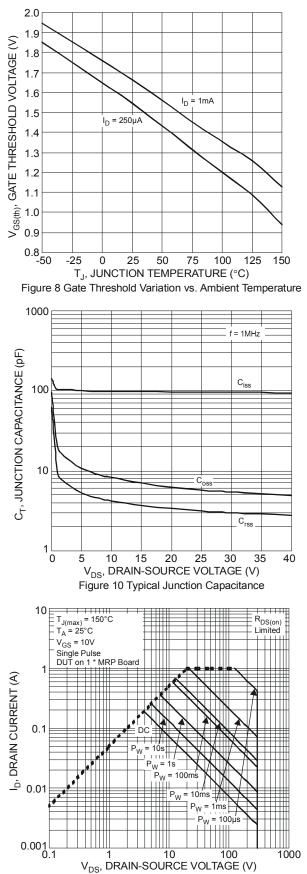
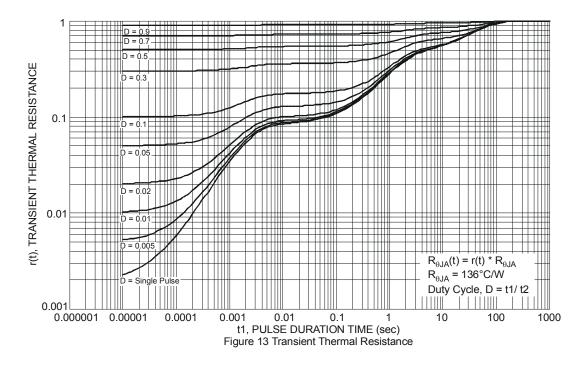


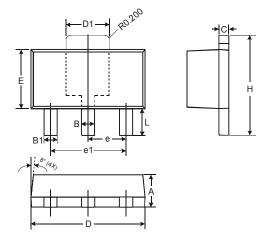
Figure 12 SOA, Safe Operation Area





Package Outline Dimensions

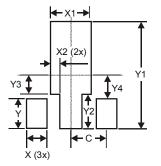
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



SOT89					
Dim	Min	Max			
Α	1.40	1.60			
В	0.44	0.62			
B1	0.35	0.54			
С	0.35	0.43			
D	4.40	4.60			
D1	1.52	1.83			
Е	2.29	2.60			
е	1.50 Typ				
e1	3.00 Typ				
Η	3.94	4.25			
L	0.89	1.20			
All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)			
Х	0.900			
X1	1.733			
X2	0.416			
Y	1.300			
Y1	4.600			
Y2	1.475			
Y3	0.950			
Y4	1.125			
С	1.500			



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